Belle II Experiment

Yutaka USHIRODA (IPNS, KEK) KEKB Review Meeting Feb. 7, 2011

Outline

- Introduction
- Detector Design
- Machine-Detector issues
- Construction Cost and Schedule
- Summary

Primary Target of KEKB/Belle

... was to confirm Kobayashi-Maskawa mechanism.





... and was so successful.

Hot news from Belle in the past

333 physics publications



- 1. Precise determination of SM (CKM)
- 2. Some unexpected observations such as new hadronic resonances (possible, but omitted in SM)
- 3. (Yet unclear) hints of new physics (impossible in SM, possible in NP)





Luminosity prospect



7



Belle II Collaboration



13 countries/regions, 57 institutes, 384 collaborators (Jan. 2011)

Belle II Organization



Tsukuba-hall webcam



Beam Pipe and Vertex Detector extraction: on Nov. 10, 2010 Belle Detector Roll-out: Dec. 9, 2010 End-caps, CDC, B-ACC, TOF extraction: in Jan. 2011



Technical Design Report

- arXiv:1011.0352: <u>http://arxiv.org/abs/1011.0352</u>
 KEK Report 2010-1:
- KEK Report 2010-1: http://www-lib.kek.jp/cgi-bin/kiss_prepri.v8? KN=201024001&OF=8.
- Belle II web page: http://b2comp.kek.jp/~twiki/pub/Organization/B2TDR/B2TDR.pdf

Reviewed by BPAC members + external experts in May and in Nov. Printed in Nov.



Vertex Detector



	Belle II	Belle
Beam Pipe	r = 10mm	15mm
DEPFEI		
Layer 1	r = 14mm	
Layer 2	r = 22mm	
DSSD		
Layer 3	r = 38mm	20mm
Layer 4	r = 80mm	43.5mm
Layer 5	r = 115mm	70mm
Layer 6	r = 140mm	88mm

PXD (DEPFET)

Each pixel is a p-channel FET on a completely depleted bulk

A deep n-implant creates a potential minimum for electrons under the gate ("internal gate")

Signal electrons accumulate in the internal gate and modulate the transistor current ($g_q \sim 400 \text{ pA/e}^-$)

Accumulated charge can be removed by a clear contact ("reset")

Fully depleted: => large signal, fast signal collection

Low capacitance, internal amplification: => low noise

High S/N even for thin sensors (50µm)

Rolling shutter mode (column parallel) for matrix operation => 20 µs frame readout time => Low power (only few lines powered)



DEPFET:

http://aldebaran.hll.mpg.de/twiki/bin/view/DEPFET/WebHome

DEPFET for Belle II



Power consumption in sensitive area: $0.1W/cm^2 =$ air-cooling sufficient

Test System



New switcher and DCD is tested with a DEPFET PXD5 matrix So far the system reaches 120ns sampling time with 40nA (~ 100 electrons) noise Some fine tuning needed to reach full speed (<100ns) (tests started 2 weeks ago)

Side remark: flipping and bump bonding of DCDB in adapter board worked without problems

SVD (DSSD)

HPK resumed DSSD production with 6" wafers Two types of rectangular sensors and Trapezoidal sensors for slanted part (still under discussion)





Flex PCBs and APV25



First prototype ladder



A prototype ladder using the first 6 inch DSSD from HPK has been assembled and tested.





Test chamber fabrication for 3D TRG study





with current Belle AMP







Time of Propagation Counter (TOP)



- Quartz radiator
 - $2.6m^{L} \times 45cm^{W} \times 2cm^{T}$
 - Excellent surface accuracy

MCP-PMT

- Hamamatsu 16ch MCP-PMT
 - Good TTS (<35ps) & enough lifetime
 - Multialkali photo-cathode → SBA



TOP (Barrel PID)

- Beam test done in 2009
 - # of photons consistent
 - Time resolution OK _









Quartz Radiator



Test beam result





Clear Cherenkov image observed

Cherenkov angle distribution



6.6 $\sigma_{\pi/K}$ at 4GeV/c !



Upgrade of ECL

For Day 1

 Upgrade electronics to do waveform sampling & fitting
 Upgrade crystals for end caps (pure CsI + photomultiplier as the baseline)



- Belle II can get advantage in π^0 and soft photon-detection efficiency and resolution in comparision with LHCb experiment
- Modify electronics for the barrel.
- Pipe-line readout with waveform analysis:
- 16 points within the signal are fitted by the signal function F(t):

 $F(t) = A f(t - t_0)$

A - amplitude of the signal and t_0 - time of the signal,

$$\chi^{2} = \sum (y_{i} - A f(t_{i} - t_{0})) S_{ij}^{-1} (y_{i} - A f(t_{i} - t_{0}))$$

- Both amplitude and time information are reconstructed:
- Next stage: Replace the CsI(Tl) by the pure CsI crystals in endcaps.

New shaper/readout boards



KLM: K_L&Muon detector

RPC \rightarrow Scintillator (End cap) also inner 1, 2, or 3 layers of Barrel(?)



GENERAL LAYOUT

- One layer: 75 strips (4 cm width)/sector
- 5 segments
 1 segment = 15strips
- Two orthogonal layer = superlayer
- F&B endcap KLM:
 - Total area $\sim 1400 \text{ m}^2$
 - 16800 strips
 - the longest strip 2.8 m; the shortest 0.6 m
- WLS fiber in each strip
- Hamamatsu MPPC at one fiber end
- mirrored far fiber end



Test modules adjacent to Belle KLM (2008)



EKLM Module-O assembled in ITEP into the frame mock-up



Close view of frame support structure and strips with SiPM connectors



Close view of strips. Segment's plastic plates are easily seen



Machine-Detector issues

✓ IR design → Tuesday morning

- ✓ Beam Background → Tuesday morning
- Machine commissioning strategy
 Injection veto and PXD
 Beam energy asymmetry (settled)
 Detector rotation

Machine commissioning strategy

Our BG estimation (MC/extrapolation) has large uncertainty.
 We don't like to burn our precious detectors before taking data.

3. We won't roll-in Belle II until we are confident about the BG level.

We will prepare dedicated detector (BEAST II) for machine commissioning to monitor the BG level and compare with our estimation.



Machine parameters for BEAST II must be close enough to the design values so that natural extrapolation would work. Unpredictable jump should be avoided. (somewhat small beam size, some beam current and some luminosity needed)

BEAST II with Solenoid magnet (?)

Discussion started

Injection veto



- Two phases
 - First phase : veto n turns completely W0 = n * 10 usec n = 10~100
 - Second phase : veto periodically W1 = ∼1 usec

 $m \sim 300$

• Three parameters (n, m, W1) : SKEKB depen

Level 1 trigger is blocked after injection because BG is too high. → dead-time Suppose n = 100, W1=1µs and m=300, 6.5% dead-time @ 50Hz injection.

DEPFET pixel detector integrates data for 20µs. = 2 revolutions of noisy bunches.

Pixels are all exposed till the end of 2nd phase (4ms) 20% dead-time @ 50Hz injection.

Trying to increase the frame rate ($20\mu s \rightarrow 5\mu s$), but still 10% dead-time (2) 50Hz injection.

Any ideas

to reduce injection repetition rate (by reinforcing injectors?) to achieve quiet injection, fast background dumping are welcome.

LER Beam Energy (settled)

3.5GeV \rightarrow 4GeV to mitigate Touschek lifetime. We are not so happy (25-30% loss in TCPV, 6% gain in full-recon.).



Detector Rotation

Two beams have finite crossing angle (83mrad). Belle solenoid axis must be bisector of the angle, but now it is not. Either Belle or two rings must be rotated.



Rotation is technically possible.

Additional cost (very preliminary estimate: 3 oku yen)

Possible damage in detectors (?)

Concern from bad experience of buckled CsI container when constructing Belle.

We will rotate Belle IF two rings cannot be rotated after all. Cost to be covered by machine group.

Belle II Construction Schedule

					2	010								203	11								2	201	2									20	13									20	014	4				
		1	2 3	3 4	5 6	57	8 9) 1(111	21	2	3 4	5	6	78	3 9	10	111	21	L 2	3	4	5	6	7 8	3 9) 1	(11	112	1	2 3	3 4	5	6	7	8 9	91	(1	112	1	2	3 4	4 !	5 6	5 7	8 7	9	10	11	12
Belle roll-out																																																		
Belle disasser	m																																																	
Rotation																																				?														
E-KLM	R&D	R&I	D																																															
	Production									Str	ip pi	rodu	ctio	n, fi	ber c	lue	ing																																	
	Installation																					As	sem	ıblv.	. Ins	stall	atic	on																						
B-KLM	R&D					R&	D																																											
	Production																																																	
	Installation																										A	ssei	mbl\	/. In	stall	atio	n																	
ECL	Prototyping, evaluation	Pro	totv	ping	Eva	luatio	n of	read	out	elect	roni	cs																																	-					
	Production														С	onn	ect	or-B				Ba	rrel	ele	ctro	nics										Ē	ndo	cap	elec	tro	nics									
	Installation																																																	
A-RICH	Aerogel	R&	D																							-			Pro	oduc	tion														-					
	HAPD	R	ם ח									P	rodu	ictic	n															- circite															-					
	ASIC	R	ח									_	loui	ictic							Pr	odu	ictio	'n																					-					
	Installation																																																	
	motanation																-				-																													
TOP	Quartz Bar	Tes	t pr	oduc	tion	eval	atio	n									Dr	oduc	tion																										-					
101		Tee	t pro	oduo	tion,	ovel		Dro	odu	uctiv	h							ouuc	uon																										-	_				
		Tes	st pro	oque	uon,	eval	allo		Juu	Cure																											_	_		_					-	_		-		
	Installation			_						_		_					-				-			_													_			_					-			-		
CDC	Oh anala an										bri	cot	ion																												_		_					-		
CDC	Chamber	Des	sign							Fa	IDLI	cat	.ion																														_							
	Readout electronics	R&I	D																								Р	roc	auc	τιο	n							_					_	_	_		_	_		
																									_	_		_			_							_						_	_		_			
SVD	Sensor	Eva	aluat	lion				Pro	odu	ictio	on																																							
	Hybrid	Pro	toty	ping	and	Evalu	atio	n			F	Proc	duc	ctic	n																																			
	Ladder															A	sse	emb	ly																															
	Ladder mount																													l	_adc	ler r	mou	unt																
PXD	Sensor	Pro	totv	pina.	test			I	Desi	ian o	fPX	(D7 ((fina	l ve	rsior	P	XD	7 p	roc	es	sin	na.	thi	inn	ind	a																								
	ASIC	Pro	toty	pina.	test													SW.	D	HP.	. D(CD																												
	Module																																Mo	odul	e pi	rodı	uctio	on												
	Module mount																									-														mc	dul	e m	0		-					
									-							-	-				-				-	+	-	-		-	-	-			+			-						-	-					
Ream nine		D.2		value	ation														E	ab	ric	ati	on												-										-					
Dearn pipe		TXX	э, е	value	auon																TTC.	erel																-	+						+-		-	-		
BDTDXDTC//D	Integration	+	-			+		+	-							-	-		-	-	-				-	-	+-	-		-	+	-			+	-	-	+	+		-	-				-	-	-		
	Installation	+				+											-		-		-					-	-								-			-												
	matallation																																																	

Construction Cost

Cost profile in FY2011-2014



~40 Oku yen in three-four years

(w/o comp.)

¹/₂ covered by KEK, ¹/₂ by collaborating institutes

Summary

- SuperKEKB/Belle II with L=8×10³⁵ cm⁻²s⁻¹is can explore many fruitful flavor physics in coming 10-15 years.
- Belle detector disassembly by end of Jan. as scheduled.
- Detector R&D, part of construction going on. On schedule so far.
- Several machine-detector issues to be cleared. Close cooperation of two groups is necessary.

Backup

Super B Factories

- Although there exist interesting possible hints for the NP at the present B factories, all the results are consistent with the SM.
- NP should exist at the higher energy scale, possibly in TeV region considering the hierarchy problem → LHC will discover it.
- Super B factories can help the identification of the NP,
- i.e. whether it is SUSY or others, or how SUSY breaking occurs.

							-
		mSU	MSSI	$M+v_R$	SU(5	5)+ _{VR}	U(2)
		GRA	degenerate	non- degenerate	degenerate	non- degenerate	FS
	A _{CP} (sγ)						1
	S(K* γ)				1	1	1
Ohservahles	S (ργ)				✓	✓	✓
a Super B	S(ϕK_S)				1	✓	✓
actories or other	$S(B_s \rightarrow J/\psi \phi)$				1	1	1
experiments	μ→eγ		√		1	1	?
	τ→μγ		✓	1	1	1	?
\checkmark	τ→еγ			1		1	?

SUSY scenario

Physics with 50(75) ab⁻¹

Two recent publications:

- Physics at Super B Factory (Belle II) arXiv:1002.5012
- SuperB Progress Reports: Physics (SuperB) arXiv:1008.1541

In addition to the topics in this talk,

- Photon polarization of $B \rightarrow K^* \gamma$.
- $B \rightarrow K^{(*)}vv$.
- CPV in D.
- \bullet LFV in τ decay.
- ...





$B \rightarrow K^* \gamma$ t-dependent CPV

 $P(B\uparrow 0 \to f; \Delta t) = e\uparrow -|\Delta t| /\tau/4\tau [1 + S\downarrow CP\uparrow f \sin(\Delta m\Delta t) + A\downarrow CP\uparrow f \cos(\Delta m\Delta t)]$

SM: $|S\downarrow CP\uparrow K\downarrow S\pi\uparrow 0\gamma|\approx (2m\downarrow s/m\downarrow b)\sin 2\Phi\downarrow 1\approx 0.04$

Left-Right Symmetric Models: $|S\downarrow CP\uparrow K\downarrow S\pi\uparrow 0\gamma|\approx 0.67\cos 2$ $\Phi\downarrow 1\approx 0.5$

D. Atwood et al., PRL79, 185 (1997)

 $S \downarrow CP \uparrow K \downarrow S \pi \uparrow 0 \gamma = \\ -0.15 \pm 0.20 \\ A \downarrow CP \uparrow K \downarrow S \pi \uparrow 0 \gamma = \\ -0.07 \pm 0.12$

HFAG, Winter'09

 $σ(S\downarrow CP\uparrow K\downarrow S π \uparrow 0 γ) = 0.09@$ 5ab $\uparrow -1$ 0.03@50ab $\uparrow -1$

(~SM prediction)



LFV and New Physics



- . SUSY + Seasaw
- Large LFV
- bkg. from ee $\rightarrow \tau \tau \gamma$ (U.L. \propto 1/VL)

el	Br(τ→μγ)
10 ⁻⁷	10 ⁻⁹
10 ⁻⁸	10 ⁻¹⁰
10 -9	10 ⁻¹⁰
10 ⁻⁹	10 ⁻⁸
10 ⁻¹⁰	10 ⁻⁷
	el 10 ⁻⁷ 10 ⁻⁸ 10 ⁻⁹ 10 ⁻⁹ 10 ⁻¹⁰



• Neutral Higgs mediated decay.

 $\tau \rightarrow 3l, l\eta$

Important when MSUSY >> EW scale



Comparison with LHCb

	Belle	Belle II	Belle II	LHCb	Advantage:
	~ 0.5 ab ⁻¹	5 ab-1	50 ab-1	10 fb ⁻¹ [5yrs]	LHCb
ΔS(φK _S)	0.22	0.073	0.029	0.14	 Modes where the states are charged
ΔS(η'K _S)	0.11	0.038	0.020		• B _c
ϕ_s from S(J/ $\psi\phi$)				0.01	• Β _c , Λ _b
S (K*γ)	0.36	0.12	0.03		•
S (ργ)	0.68	0.22	0.08		
$\Delta B/B(B \rightarrow \tau v)$	3.50	10%	3%		
$B_s \rightarrow \mu\mu$	•	•	•	5σ @ 6 fb⁻¹	B factories
$\tau \to \mu \gamma ~[\times_{10}^{-9}]$	<45	<30	<8		 Modes with γ, π°. Modes with γ.
τ → μμμ [×10 ⁻⁹]	<209	<10	<1		• τ decays.
φ ₂	11 ⁰	2 ⁰	1 ⁰	4.5°	• K _s vertex.
φ ₃	160	6°	2 ⁰	2.4 ⁰	

• Modes where the final states are charged only.

ASICs for control and readout



Switcher

Control of gate and clear 32 x 2 channels Switches up to 30V AMS 0.35 µm HV technology Tested up to 36 Mrad

DCDB

Amplification and digitization of DEPFET signals 256 input channels 8-bit ADC per channel 92 ns sampling time UMC 189nm Rad hard design

DHP

Signal processor Common mode correction Pedestal subtraction 0-supression Timing and trigger control IBM 90 nm Rad hard design ½ size (32 channel) test chip

All three chips fabricated and successfully tested

Test Beam in 2009 (ILC version)

Array of 6 DEPFET modules



Radiation Damage

DEPFET based on a MOS structure problem with ionising radiation: Creation of fixed (positive) charges in the oxide layer and at the interface Attracts electrons at the Si/SiO₂ interface Need more negative gate voltages to compensate => Shift of transistor threshold







D (krad)

extrapolation to 10Mrad through "black star points"

6000

8000

10000

4000

wafer 2 up to 1Mrad

wafer 2 up to 10Mrad

2000

0.6

0.0

0



Performance of 1-bar/2-bar TOP



Incident angle fluctuation (1mrad) Timing fluctuation (25ps)

Performance similar (weighted) for physics case studies

Configuration choice (May, 2010)

- Two configurations show similar performance
- 1-bar configuration shows stable performance as a function of increased timing jitter. 2-bar need precise, continual timing calibration during experiment operation.
- 1-bar case has larger forward acceptance and requires readout only in the backward direction. (forward cable routing is very crowded)
- We chose the <u>1-bar configuration as baseline</u>, with 2-bar as a backup option, due to these practical considerations.

MCP-PMT photocathode

- Typical QE at max.
 - Bialkali (SBA); 28%
 - Multialkali (MA); 24%
- Performance check by simulation
 - Difference QE distribution makes different chromaticity effect.
- SBA shows better performance.
 - \rightarrow Chose SBA.
 - We push HPK to improve QE during production.





MCP-PMT: improvement in lifetime

Protections against -lon feedback -Neutral gas were effective.



60

End-cap Particle Identification

- Ring imaging Cherenkov counter based on silica aerogel radiator
 - Space limited -> proximity focusing with expansion distance of 20 cm
 - Requirements
 - Transparent silica aerogel
 - Photo-detector
 - Single-photon sensitivity
 - Pixel 5x5mm²
 - Operational in 1.5T
 - Compact
 - Readout electronics
 - ~70K channels



n=1.05 aerogel $|\sigma_c(\pi)-\sigma_c(K)| = 23 \text{ mrad at P=4GeV/c}$

Target: More than 4 $\sigma \pi/K$ separation at 4 GeV/c

Novel "focusing" radiator

Possible only with aerogel !

Simple accumulation of radiator layer gives more photons, but degrades PID performance



HAPD QE Improvement HAPD QE has been greatly improved with "super bialkali" technology by Hamamatsu.



Studies to Reduce Neutron Damage

Thinner APD to reduce neutron induced lattice deficits





- Contribution of N-layer (hole) is about 1/100 of that of P-layer (e).
 - \rightarrow Thinner P layer
- Improvement confirmed with APD irradiation tests
 - → presumably this improves HAPD tolerance, too
 ⁶⁴
 - ightarrow HAPD irradiation test is under way.

Status of Readout Electronics for Aerogel RICH





~74mm (~final size)

Trial production of the front end board in progress (Ljubljana).

Prototype Merger board will be designed in this fiscal year.

The design of the next version of the ASIC (So₃) has just started.

- Shorter shaping time.
- Production schedule depends on HAPD & front-end board development



ECL Collector module

Role of the module:

- Configure Xilinx FPGA on ShaperDSP modules
- Synchronize sampling process on all 12 ShaperDSP modules
- Collect data from 12 connected ShaperDSP modules
- Calibration signal generation
- Interface with remote PC for stand-alone operation
- Provide interface with Belle II TTD and DAQ

Status:

- Prototype module ... produced
- Remote firmware configuration on ShaperDSP ... established
- Interface with remote PC ...established
- Calibration signal generation ... established
- Rocket-I/O ... to be tested soon





Shaper DSP module

Key features:

- 16 channels per module
- $\tau=0.5\mu s$ shaper
- FADC
- Waveform fitting

Output pulse height, timing, and quality of fit

• Fast shaper + Variable gain amp. for trigger output.



Status:

- Prototype module ... produced
- New revision ... to be submitted in this FY

	Belle	Belle II
Linearity	<0.5%	<0.3%
Shaping time	ıμs	o.5µs
ENE	~200keV	~300keV
ENE (w/ pile-up noise)	500-1000keV	400-600keV



Most critical path of each subsystem

			new companies
	Most crucial item	Necessary time	$(\rightarrow 4 \text{ months})$
BP	Design study, Beryllium pipe production	1-1.5 years, 1 year	
PXD	Sensor production	1.5 years	
SVD	Sensor production	2 years	
CDC	Drilling small cell end-plate	9 months after get	ting skilled
ТОР	Quartz bar production	2.3 years	
A-RICH	HAPD production	1.3 years	v companies (in US)
ECL	(To exchange pre-amps If we do so)		
KLM	Scintillator bar production	1.5 years,	

Simpler Repipe by

